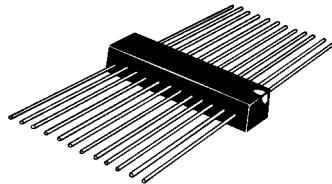


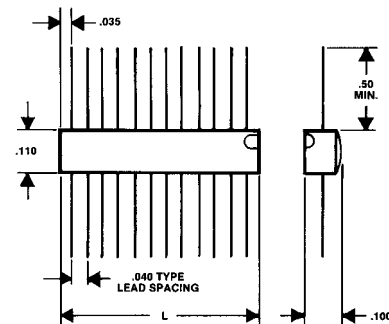
Miniature High Voltage Diode Array

Features

- PIV = 1200 VDC
- IR @23 °C 500 VDC 10 nano amps Max.
- Junction capacitance @ 23 ° 0.35 pF Max. @ 500 VDC
- Recovery Time @ 23 °C 1.5 micro sec. @ IF = 10 ma
- Recovery Time @ 23 °C 0.5 micro sec. @ IF = 2.0 ma
- Operating Temp. + 55 °C To -54 °C
- Storage Temp. + 85 °C To - 70 °C



MECHANICAL
 • Lead Diameter .015 Max.
 • Lead Material - Silver
 • Encapsulant - Epoxy



K & M PART NO.	NO. OF DIODES	DIM L
107-276	12	.510
107-274	8	.350
107-273	6	.270
107-291-04	4	.190
107-291-02	2	.110

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